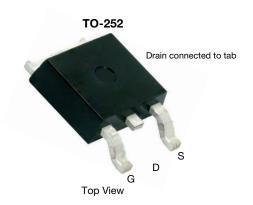


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Vishay Siliconix

Automotive P-Channel 30 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V _{DS} (V)	-30			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.00320			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.00520			
I _D (A)	-100			
Configuration	Single			
Package	TO-252			

FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % R_q and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



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P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V _{DS}	-30	V
Gate-source voltage		V_{GS}	± 20	
Continuous drain current	T _C = 25 °C ^a	- I _D	-100	
	T _C = 125 °C		-94	
Continuous source current (diode conduction) a	I _S	-100	Α	
Pulsed drain current ^b		I _{DM}		-300
Single pulse avalanche current	L = 0.1 mH	I _{AS}	-41	
Single pulse avalanche energy	L = 0.1 IIIII	E _{AS}	84	mJ
Maximum power dissipation ^b	T _C = 25 °C	P _D	136	W
	T _C = 125 °C		45	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount c	R _{thJA}	50	°C/W	
Junction-to-case (drain)		R _{thJC}	1.1	G/VV	

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		-30	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	V _{GS} , I _D = -250 μA	-1.5	-2.0	-2.5	V
Gate-source leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 100	nA
		$V_{GS} = 0 V$	$V_{GS} = 0 V$ $V_{DS} = -30 V$		-	-1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = -30 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	-	-	-50	μΑ
		V _{GS} = 0 V	V _{DS} = -30 V, T _J = 175 °C	-	-	-250	
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	V _{DS} ≥ -5 V	-50	-	-	Α
		V _{GS} = -10 V	I _D = -30 A	-	0.00263	0.00320	
Drain aguras en eteta registance 3	В	V _{GS} = -10 V	I _D = -30 A, T _J = 125 °C	-	-	0.00438	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -10 V	I _D = -30 A, T _J = 175 °C	-	-	0.00502	Ω
		V _{GS} = -4.5 V	I _D = -25 A	-	0.00425	0.00520	
Forward transconductance b	9 _{fs}	V _{DS} =	= -15 V, I _D = 30 A	-	98	-	S
Dynamic ^b							
Input capacitance	C _{iss}			-	11 085	15 000	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = -25 V, f = 1 MHz	-	1342	1900	pF
Reverse transfer capacitance	C _{rss}			-	1181	1600	
Total Gate Charge ^c	Qg			-	186	280	
Gate-source charge ^c	Q _{gs}	$V_{GS} = -10 \text{ V}$	$V_{DS} = -15 \text{ V}, I_{D} = -100 \text{ A}$	-	28	-	nC
Gate-drain charge ^c	Q _{gd}			-	28	-	
Gate resistance	R _g		f = 1 MHz		3.5	5.3	Ω
Turn-on delay time ^c	t _{d(on)}			-	16	25	
Rise time ^c	t _r	V _{DD} =	-15 V, R _L = 0.2 Ω	-	204	310	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong -100 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$		-	126	190	ns
Fall time ^c	t _f			-	72	110	
Source-Drain Diode Ratings and Character	teristics ^b						
Pulsed current ^a	I _{SM}			-	-	-300	Α
Forward voltage	V_{SD}	I _F = -30 A, V _{GS} = 0 V		-	-0.8	-1.5	V
Body diode reverse recovery time	t _{rr}	I _F = -40 A, di/dt = 100 A/μs		=	66	135	ns
Body diode reverse recovery charge	Q _{rr}			=	100	200	nC
Reverse recovery fall time	ta			-	31	-	
Reverse recovery rise time	t _b			-	35	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-3.4	-	Α

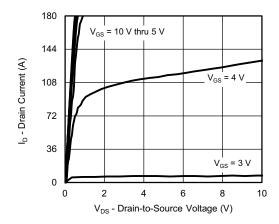
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

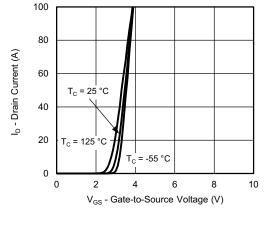
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



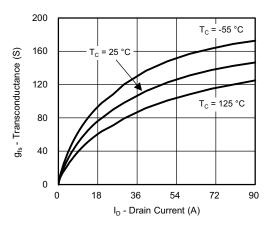
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



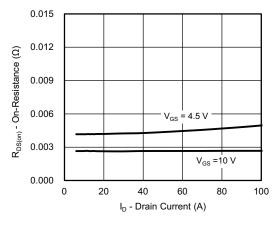
Output Characteristics



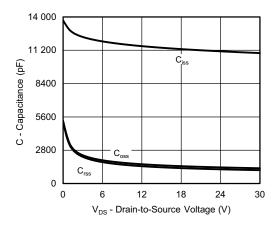
Transfer Characteristics



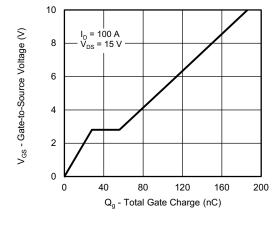
Transconductance



On-Resistance vs. Drain Current



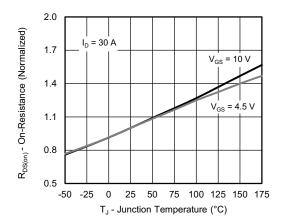
Capacitance



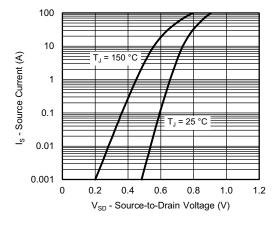
Gate Charge



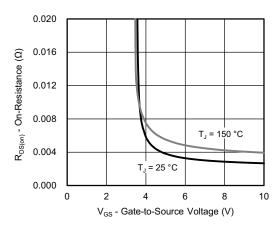
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



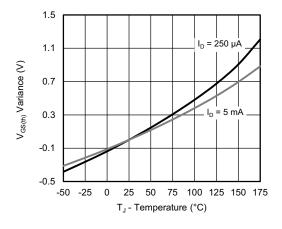
On-Resistance vs. Junction Temperature



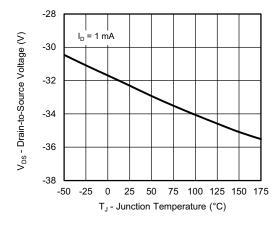
Source Drain Diode Forward Voltage



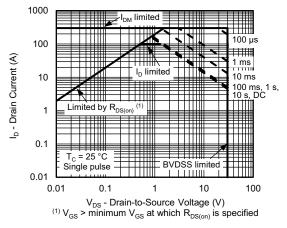
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



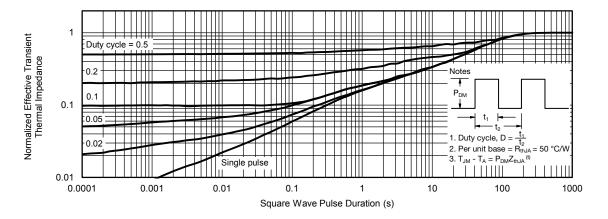
Drain Source Breakdown vs. Junction Temperature



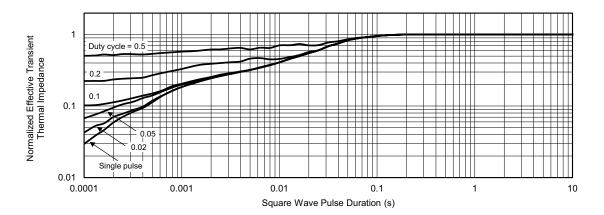
Safe Operating Area



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

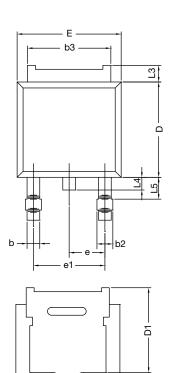
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to- Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

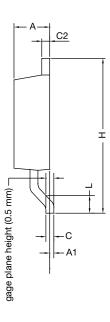
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?76011.





TO-252AA Case Outline





	MILLIN	METERS	INC	HES	
DIM.	MIN.	MAX.	MIN.	MAX.	
Α	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	4.10	-	0.161	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28 BSC		0.090	BSC	
e1	4.56 BSC		0.180	BSC	
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.01	1.52	0.040	0.060	
ECN: T13-0592-Rev. A, 02-Sep-13					

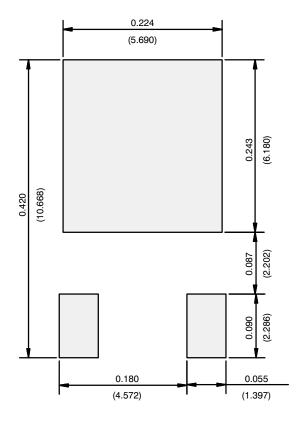
DWG: 6019

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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